BUK581-60A

GENERAL DESCRIPTION

N-channel enhancement mode logic level field-effect power transistor in a plastic envelope suitable for surface mount applications.

The device is intended for use in automotive and general purpose switching applications.

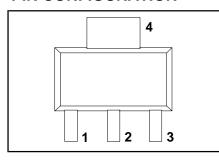
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V _{DS} I _D Ptot T _j R _{DS(ON)}	Drain-source voltage Drain current (DC) Total power dissipation Junction temperature Drain-source on-state resistance; V _{GS} = 5 V	60 1.5 1.5 150 0.40	V Α Ψ C Ω

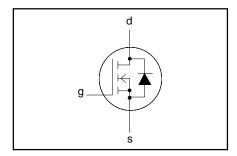
PINNING - SOT223

PIN	DESCRIPTION	
1	gate	
2	drain	
3	source	
4	drain (tab)	

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{DS}	Drain-source voltage	-	-	60	V
V _{DGR}	Drain-gate voltage	$R_{GS} = 20 \text{ k}\Omega$	-	60	V
$\begin{array}{c} V_{DGR} \\ \pm V_{GS} \end{array}$	Gate-source voltage	-	-	15	V
I _D	Drain current (DC)	$T_{amb} = 25 ^{\circ}C$	-	1.5	Α
I _D	Drain current (DC)	$T_{amb} = 100 ^{\circ}C$	-	1	Α
I _{DM}	Drain current (pulse peak value)	$T_{amb}^{amb} = 25 ^{\circ}C$ $T_{amb} = 25 ^{\circ}C$	-	6	Α
P _{tot}	Total power dissipation	$T_{amb} = 25 ^{\circ}C$	-	1.5	W
T _{stq}	Storage temperature	-	- 55	150	°C
T	Junction Temperature	-	-	150	°C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-sp} R _{th j-amb}		Mounted on any PCB . Mounted on PCB of Fig.18		14 -	17 85	K/W K/W

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¹ Temperature measured at solder joint on drain tab.

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STATIC CHARACTERISTICS

T_i = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{(BR)DSS}$	Drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_{D} = 0.25 \text{ mA}$	60	-	-	V
	Gate threshold voltage Zero gate voltage drain current	$\begin{array}{l} V_{DS} = V_{GS}; \ I_D = 0.1 \ \text{mA} \\ V_{DS} = 60 \ \text{V}; \ V_{GS} = 0 \ \text{V}; \\ V_{DS} = 60 \ \text{V}; \ V_{GS} = 0 \ \text{V}; \ T_j = 125 \ ^{\circ}\text{C} \\ V_{GS} = \pm 15 \ \text{V}; \ V_{DS} = 0 \ \text{V} \\ V_{GS} = 5 \ \text{V}; \ I_D = 1.5 \ \text{A} \end{array}$	1.0 - - - -	1.5 1 0.1 10 0.28	2.0 10 1.0 100 0.40	V μA mA nA

DYNAMIC CHARACTERISTICS

T_i = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
g _{fs}	Forward transconductance	$V_{DS} = 25 \text{ V}; I_{D} = 1.5 \text{ A}$	1.0	2.2	-	S
C _{iss} C _{oss} C _{rss}	Input capacitance Output capacitance Feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 25 \text{ V}; f = 1 \text{ MHz}$	- - -	170 60 25	300 100 50	pF pF pF
$\begin{array}{c} t_{\text{d on}} \\ t_{\text{r}} \\ t_{\text{d off}} \\ t_{\text{f}} \end{array}$	Turn-on delay time Turn-on rise time Turn-off delay time Turn-off fall time	$\begin{array}{l} V_{DD} = 30 \text{ V; } I_{D} = 3 \text{ A;} \\ V_{GS} = 5 \text{ V; } R_{GS} = 50 \Omega; \\ R_{gen} = 50 \Omega \end{array}$	- - -	7 45 15 25	10 55 25 35	ns ns ns ns

REVERSE DIODE LIMITING VALUES AND CHARACTERISTICS

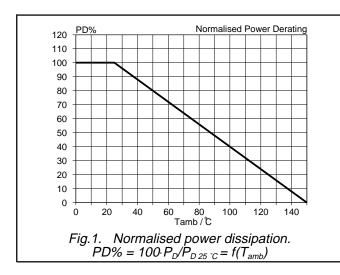
T_i = 25 °C unless otherwise specified

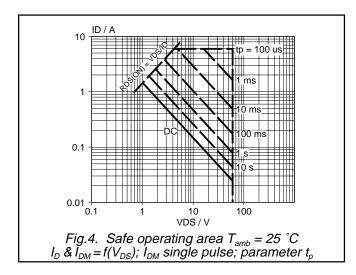
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_{DR}	Continuous reverse drain current	-	-	-	1.5	Α
${f I}_{ m DRM} \ {f V}_{ m SD}$	Pulsed reverse drain current Diode forward voltage	$I_F = 1.5 \text{ A}; V_{GS} = 0 \text{ V}$	-	- 0.85	6 1.1	A V
t _{rr} Q _{rr}	Reverse recovery time Reverse recovery charge	$I_F = 1.5 \text{ A}; -dI_F/dt = 100 \text{ A/}\mu\text{s}; \ V_{GS} = -10 \text{ V}; \ V_R = 30 \text{ V}$		30 50	-	ns nC

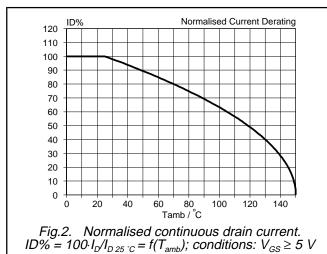
AVALANCHE LIMITING VALUE

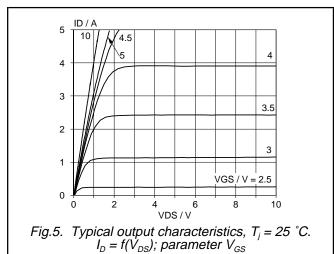
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Drain-source non repetitive unclamped inductive turn-off energy	$I_D = 1.5 \text{ A} \; ; \; V_{DD} \le 25 \text{ V} \; V_{GS} = 5 \text{ V} \; ; \; R_{GS} = 50 \; \Omega \; T_{amb} = 25 \; ^{\circ}\text{C}$	ı	1	10	mJ

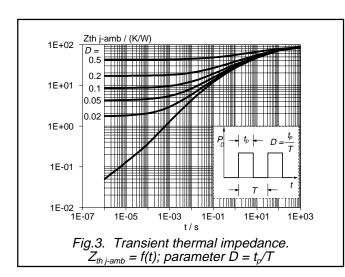
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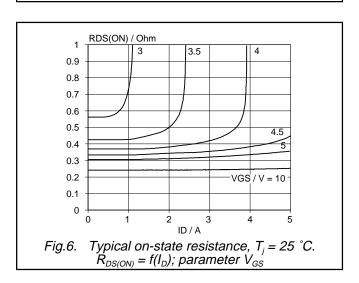




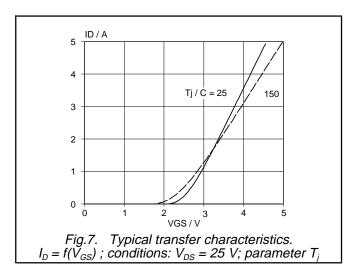


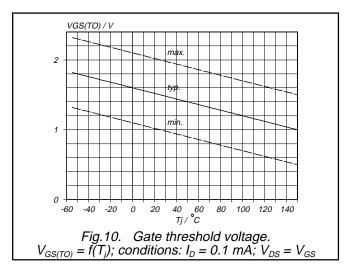


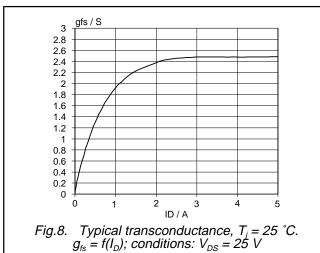


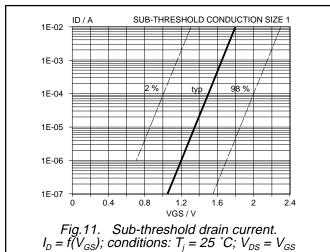


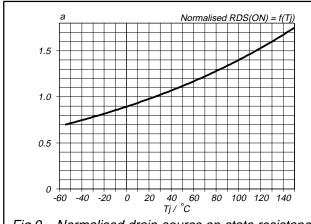
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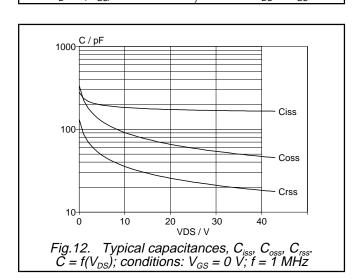
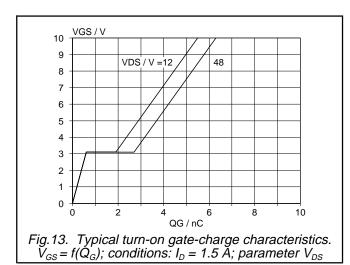
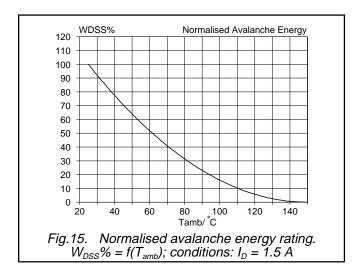
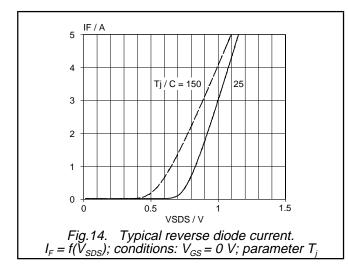


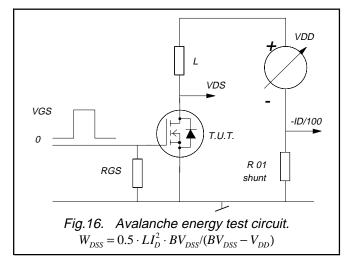
Fig.9. Normalised drain-source on-state resistance. $a = R_{DS(ON)}/R_{DS(ON)25}$ °C = $f(T_i)$; $I_D = 1.5$ A; $V_{GS} = 5$ V

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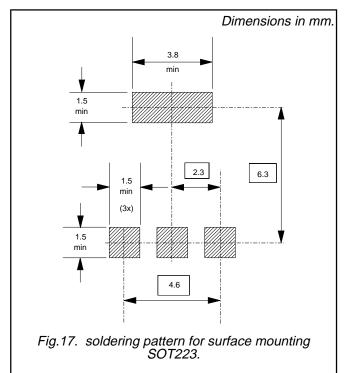






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MOUNTING INSTRUCTIONS



PRINTED CIRCUIT BOARD

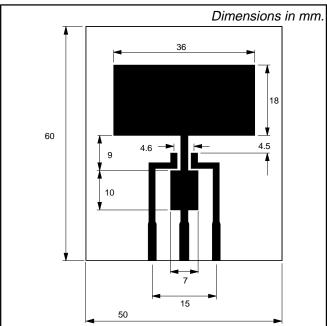
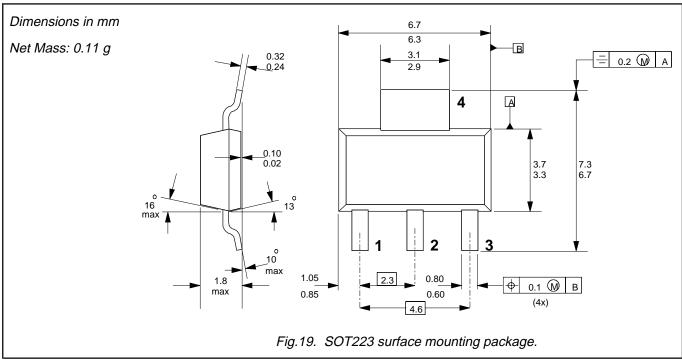


Fig.18. PCB for thermal resistance and power rating for SOT223.

PCB: FR4 epoxy glass (1.6 mm thick), copper laminate (35 µm thick).

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MECHANICAL DATA



Notes

- Observe the general handling precautions for electrostatic-discharge sensitive devices (ESDs) to prevent damage to MOS gate oxide.
 Refer to surface mounting instructions for SOT223 envelope.
 Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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